SN54LV373...J OR W PACKAGE SN74LV373...DB. DW. OR PW PACKAGE

(TOP VIEW)

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- EPIC ™ (Enhanced-Performance Implanted CMOS) 2-µ Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC}, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC}, T_A = 25°C
- ESD Protection Exceeds 2000 V Per MIL-STD-883C, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 250 mA Per JEDEC Standard JESD-17
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), Thin Shrink Small-Outline (PW), Ceramic Flat (W) Packages, Chip Carriers (FK), and (J) 300-mil DIPs

description

These octal transparent D-type latches are designed for 2.7-V to 5.5-V V_{CC} operation.

While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic

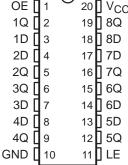
state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

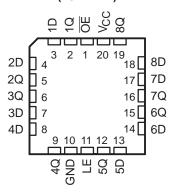
The SN74LV373 is available in TI's shrink small-outline package (DB), which provides the same I/O pin count and functionality of standard small-outline packages in less than half the printed-circuit-board area.

The SN54LV373 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LV373 is characterized for operation from –40°C to 85°C.

OE 1 20 V_{CC} 1Q 2 19 8Q 1D 3 18 8D



SN54LV373 . . . FK PACKAGE (TOP VIEW)



FUNCTION TABLE (each latch)

_				
		INPUTS	OUTPUT	
	OE	LE	D	Q
Γ	L	Н	Н	Н
	L	Н	L	L
	L	L	Χ	Q ₀
	Н	X	Χ	Z



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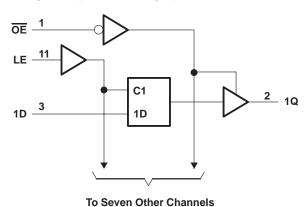
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logic symbol†

OE ΕN LE C1 3 1D 1Q 1D 5 4 2Q 2D 6 7 3D 3Q 9 8 4D 4Q 13 12 5D 5Q 15 14 6D 6Q 17 16 7Q 7D 18 19 8D 8Q

logic diagram (positive logic)



Pin numbers shown are for DB, DW, J, PW, and W packages.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Output voltage range, V _O (see Notes 1 and 2)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, I_{IK} ($V_I < 0$ or $V_I > V_{CC}$)	±20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC})	±50 mA
Continuous output current, I_O ($V_O = 0$ to V_{CC})	±35 mA
Continuous current through V _{CC} or GND	±70 mA
Maximum power dissipation at $T_A = 55^{\circ}$ C (in still air) (see Note 3): DB package	0.6 W
DW package .	1.6 W
PW package	0.7 W
Storage temperature range, T _{sto}	–65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
 - This value is limited to 7 V maximum.
 - 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

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recommended operating conditions (see Note 4)

			SN54L	_V373	SN74LV373		UNIT
			MIN	MAX	MIN	MAX	UNII
VCC	Supply voltage		2.7	5.5	2.7	5.5	V
VIH	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		2		V
	r light-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	3.15		3.15		V
VIL	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8		0.8	V
	Low-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		1.65		1.65	V
VI	Input voltage		0	Vcc	0	VCC	V
۷o	Output voltage		0,	VCC	0	Vcc	V
la	High lovel output ourrent	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	20	-8		-8	mA
IОН	High-level output current	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	20	-16		-16	mA
	Low level output ourrent	V _{CC} = 2.7 V to 3.6 V	V	8		8	mA
IOL	Low-level output current	Low-level output current $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		16		16	IIIA
Δt/Δν	Input transition rise or fall rate		0	100	0	100	ns/V
T _A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	\ \ \ \ +	SN54LV373	SN74LV373	UNIT	
PARAMETER	TEST CONDITIONS	v _{cc} †	MIN TYP MA	X MIN TYP MAX	UNII	
	I _{OH} = -100 μA	MIN to MAX	V _{CC} -0.2	V _{CC} -0.2		
Voн	$I_{OH} = -8 \text{ mA}$	3 V	2.4	2.4	V	
	I _{OH} = -16 mA	4.5 V	3.6	3.6		
	I _{OL} = 100 μA	MIN to MAX	0	.2 0.2		
V _{OL}	I _{OL} = 8 mA	3 V	0	.4 0.4	V	
	I _{OL} = 16 mA	4.5 V	3.0	0.55		
1.	V _I = V _{CC} or GND	3.6 V	<u> </u>	±1		
tι		5.5 V	14 ±	±1	μΑ	
lo-	$V_O = V_{CC}$ or GND	3.6 V	Q <u>+</u>	.5 ±5		
loz		5.5 V	S ±	.5 ±5	μΑ	
laa	V V == 0ND 1 0	3.6 V	8 2	20		
lcc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	2 2	20	μΑ	
ΔICC	One input at V _{CC} – 0.6 V, Other inputs at V _{CC} or GND	3 V to 3.6 V	50	500	μΑ	
	V V 0ND	3.3 V	2.5	2.5	_	
C _i	V _I = V _{CC} or GND	5 V	3	3	pF	
	Ly y ONE	3.3 V	7	7		
Co	$V_O = V_{CC}$ or GND	5 V	7.5	7.5	pF	

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

SN54LV373, SN74LV373 OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

				SN54LV373						
		V _{CC} = 5	$V_{CC} = 5 V \pm 0.5 V$		$V_{CC} = 3.3 V \pm 0.3 V$			UNIT		
			MIN	MAX	MIN	MAX	MIN M	AX		
t _W	Pulse duration, LE high		10		10 1/		118		ns	
t _{su}	Setup time, data before LE \downarrow	High or low	4	<	6111	o Pi	6		ns	
t _h	Hold time, data after LE↓	High or low	6		6	<	6		ns	

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

				SN74LV373							
			V _{CC} = 5	$V \pm 0.5 V$	V _{CC} = 3.3	$3~V\pm0.3~V$	VCC =	= 2.7 V	UNIT		
			MIN	MAX	MIN	MAX	MIN	MAX			
t _W	Pulse duration, LE high		10		10		8		ns		
t _{su}	Setup time, data before LE \downarrow	High or low	4		6		6		ns		
th	Hold time, data after LE↓	High or low	6		6		6		ns		

switching characteristics over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Figure 1)

			SN54LV373									
PARAMETER	FROM (INPUT)	TO (OUTPUT)	-	V _{CC}	V _{CC} = 5 V ± 0.5 V			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$			V _{CC} = 2.7 V	
			MIN	TYP	MAX	MIN	TYP	MAX	MIN	MAX		
	D	Q		8	16	4	11	22	<u> </u>	28	no	
^t pd	LE			11	19	, ih	15	25	M	26	ns	
t _{en}	ŌĒ	Q		15	23	. III	15	27	7/1/2	28	ns	
^t dis	ŌĒ	Q		15	23	Y	15	27		28	ns	

switching characteristics over recommended operating free-air temperature range, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

						SN74L	_V373					
PARAMETER	FROM (INPUT)		TO (OUTPUT)	V_{CC} = 5 V \pm 0.5 V			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$			V _{CC} = 2.7 V		UNIT
		(001101)	MIN	TYP	MAX	MIN	TYP	MAX	MIN	MAX		
	D	Q		8	16		11	22		28	20	
^t pd	LE	Q		11	19		15	25		26	ns	
t _{en}	ŌĒ	Q		15	23		15	27		28	ns	
^t dis	ŌĒ	Q		15	23		15	27		28	ns	

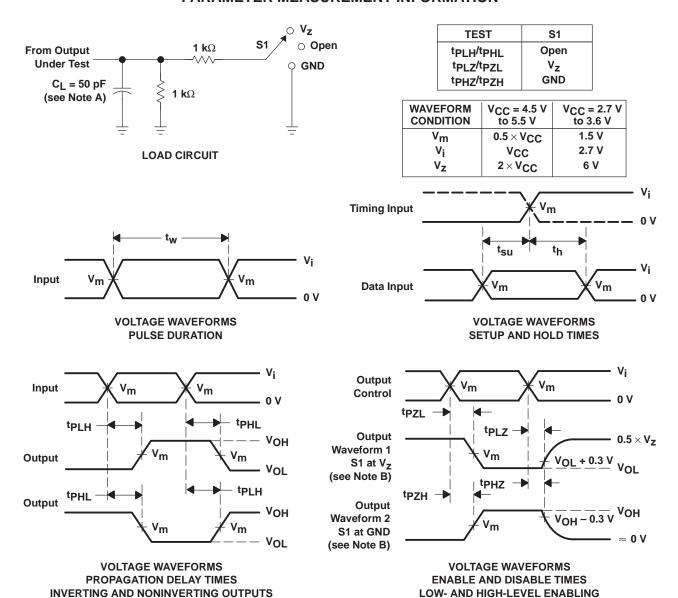
operating characteristics, T_A = 25°C

	PARAMETER	TEST CONDITIONS	VCC	TYP	UNIT	
	Outputs enabled		3.3 V	47		
	Power dissipation capacitance per latch	Outputs disabled	$C_1 = 50 \text{ pF}, f = 10 \text{ MHz}$	3.3 V	29	pF
C _{pd}		Outputs enabled	C _L = 30 pr,	5 V	112	PΓ
		Outputs disabled		5 V	62	

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PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time with one transition per measurement.
- E. tpLz and tpHz are the same as tdis.
- F. tpzL and tpzH are the same as ten.
- G. tpLH and tpHL are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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